



CSD95372BQ5M Synchronous Buck NexFET™ Smart Power Stage

1 Features

- 60 A Continuous Operating Current Capability
- 93.4% System Efficiency at 30 A
- Low Power Loss of 2.8 W at 30 A
- High Frequency Operation (up to 1.25 MHz)
- Diode Emulation Mode With FCCM
- Temperature Compensated Bi-Directional Current Sense
- Analog Temperature Output (600 mV at 0°C)
- Fault Monitoring
 - High-Side Short, Overcurrent, and Overtemperature Protection
- 3.3 and 5 V PWM Signal Compatible
- Tri-State PWM Input
- Integrated Bootstrap Diode
- Optimized Deadtime for Shoot Through Protection
- High Density SON 5 × 6 mm Footprint
- Ultra-Low Inductance Package
- System Optimized PCB Footprint
- RoHS Compliant – Lead-Free Terminal Plating
- Halogen Free

2 Applications

- Multiphase Synchronous Buck Converters
 - High Frequency Applications
 - High Current, Low Duty Cycle Applications
- POL DC-DC Converters
- Memory and Graphic Cards
- Desktop and Server VR11.x / VR12.x V-Core and Memory Synchronous Converters

3 Description

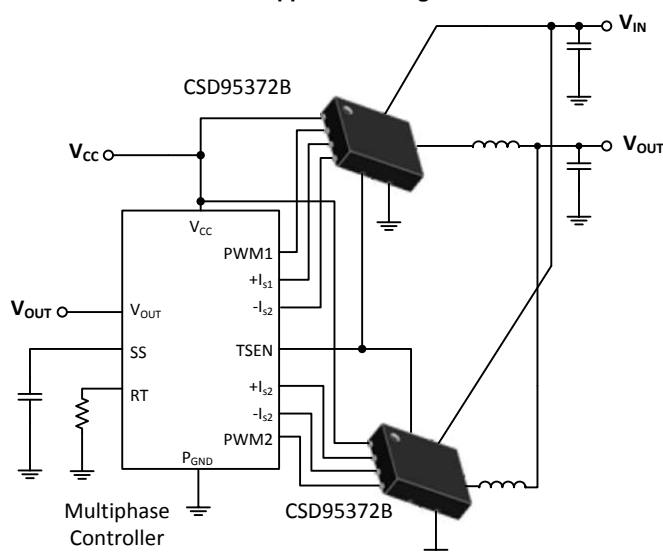
The CSD95372BQ5M NexFET™ smart power stage is a highly optimized design for use in a high power, high density Synchronous Buck converter. This product integrates the Driver IC and Power MOSFETs to complete the power stage switching function. This combination produces high current, high efficiency, and high speed switching capability in a small 5 mm × 6 mm outline package. It also integrates the accurate current sensing and temperature sensing functionality to simplify system design and improve accuracy. In addition, the PCB footprint has been optimized to help reduce design time and simplify the completion of the overall system design.

Device Information⁽¹⁾

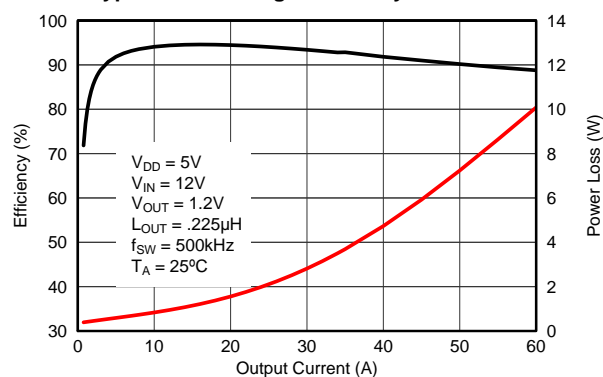
| Device | Media | Qty | Package | Ship |
|---------------|--------------|------|-------------------------------|---------------------|
| CSD95372BQ5M | 13-Inch Reel | 2500 | SON 5-mm × 6-mm Package | Tape and Reel |
| CSD95372BQ5MT | 7-Inch Reel | 250 | | |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Application Diagram



Typical Power Stage Efficiency and Power Loss



G001



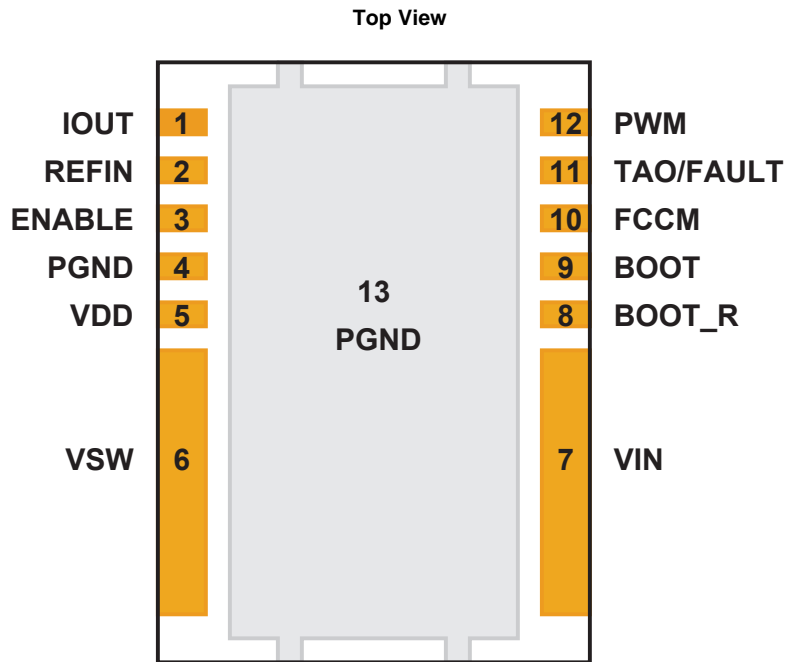
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4 Revision History

| Changes from Original (March 2014) to Revision A | Page |
|--|------|
| • Removed "input voltage up to 14.5 V" and "DualCool™ package" bullets from the Features | 1 |
| • Fixed TAO/FAULT pin function to state that TAO will be pulled up to 3.3 V in the event of thermal shutdown | 3 |
| • Added minimum ESD Ratings | 4 |
| • Increased maximum input voltage to 16 V | 4 |
| • Added table note for max input voltage | 4 |

5 Pin Configuration and Functions



Pin Functions

| PIN | | DESCRIPTION |
|------------------|--------|--|
| NAME | NUMBER | |
| BOOT | 9 | Bootstrap capacitor connection. Connect a minimum of 0.1-μF 16-V X7R ceramic capacitor from BOOT to BOOT_R pins. The bootstrap capacitor provides the charge to turn on the control FET. The bootstrap diode is integrated. |
| BOOT_R | 8 | Return path for HS gate driver, connected to V _{SW} internally. |
| ENABLE | 3 | Enables device operation. If ENABLE = logic HIGH, turns on device. If ENABLE = logic LOW, the device is turned off and both MOSFET gates are actively pulled low. An internal 100-kΩ pulldown resistor will pull the ENABLE pin LOW if left floating. |
| FCCM | 10 | This pin enables the Diode Emulation function. When this pin is held LOW, Diode Emulation Mode is enabled for sync FET. When FCCM is HIGH, the device is operated in Forced Continuous Conduction Mode. An internal 5-μA current source will pull the FCCM pin to 3.3 V if left floating. |
| IOUT | 1 | Output of current sensing amplifier. V(IOUT) – V(REFIN) is proportional to the phase current. |
| P _{GND} | 4 | Power ground, connected directly to pin 13. |
| P _{GND} | 13 | Power ground |
| PWM | 12 | Pulse width modulated 3-state input from external controller. Logic LOW sets control FET gate low and sync FET gate high. Logic HIGH sets control FET gate high and sync FET gate low. Open or High Z sets both MOSFET gates low if greater than the 3-state shutdown hold-off time (t _{3HT}). |
| REFIN | 2 | External reference voltage input for current sensing amplifier |
| TAO/ FAULT | 11 | Temperature Analog Output. Reports a voltage proportional to the die temperature. An ORing diode is integrated in the IC. When used in multiphase application, a single wire can be used to connect the TAO pins of all the IC's. Only the highest temperature will be reported. TAO will be pulled up to 3.3 V if thermal shutdown occurs. TAO should be bypassed to P _{GND} with a 1-nF 16-V X7R ceramic capacitor. |
| V _{DD} | 5 | Supply voltage to gate driver and internal circuitry |
| V _{IN} | 7 | Input voltage pin. Connect input capacitors close to this pin. |
| V _{SW} | 6 | Phase node connecting the HS MOSFET source and LS MOSFET drain – pin connection to the output inductor. |

6 Specifications

6.1 Absolute Maximum Ratings

 $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)⁽¹⁾

| | MIN | MAX | UNIT |
|--|------|-------------------------|--------------------|
| V_{IN} to P_{GND} | –0.3 | 25 | V |
| V_{IN} to V_{SW} | –0.3 | 25 | V |
| V_{IN} to V_{SW} (10 ns) | –7 | 27 | V |
| V_{SW} to P_{GND} | –0.3 | 20 | V |
| V_{SW} to P_{GND} (10 ns) | –7 | 23 | V |
| V_{DD} to P_{GND} | –0.3 | 7 | V |
| ENABLE, PWM, FCCM, TAO, IOUT, REFIN to P_{GND} | –0.3 | $V_{DD} + 0.3\text{ V}$ | V |
| BOOT to BOOT_R ⁽²⁾ | –0.3 | $V_{DD} + 0.3\text{ V}$ | V |
| P_D , Power Dissipation | | 12 | W |
| T_J , Operating Junction | –55 | 150 | $^{\circ}\text{C}$ |

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Should not exceed 7 V

6.2 Handling Ratings

| | | | MIN | MAX | UNIT |
|--------------------|---------------------------|----------------------------|-------|------|------|
| T _{stg} | Storage Temperature Range | | −55 | 150 | °C |
| V _(ESD) | Electrostatic discharge | Human Body Model (HBM) | −2000 | 2000 | V |
| | | Charged Device Model (CDM) | −500 | 500 | |

6.3 Recommended Operating Conditions

 $T_A = 25^{\circ}$ (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|---------------------|-------------------------------------|---|-----|------|------|
| V _{DD} | Gate Drive Voltage | | 4.5 | 5.5 | V |
| V _{IN} | Input Supply Voltage ⁽¹⁾ | | | 16 | V |
| V _{OUT} | Output Voltage | | | 5.5 | V |
| I _{OUT} | Continuous Output Current | V _{IN} = 12 V, V _{DD} = 5 V, V _{OUT} = 1.2 V, f _{SW} = 500 kHz, L _{OUT} = 0.225 μH ⁽²⁾ | | 60 | |
| I _{OUT-PK} | Peak Output Current ⁽³⁾ | | | 90 | A |
| f _{SW} | Switching Frequency | C _{BST} = 0.1 μF (min) | | 1250 | kHz |
| | On Time Duty Cycle | f _{SW} = 1 MHz | | 85 | % |
| | Minimum PWM On Time | | 40 | | ns |
| | Operating Temperature | | −40 | 125 | °C |

(1) Operating at high V_{IN} can create excessive AC voltage overshoots on the switch node (V_{SW}) during MOSFET switching transients. For reliable operation, the switch node (V_{SW}) to ground voltage must remain at or below the *Absolute Maximum Ratings*.

(2) Measurement made with six 10- μF (TDK C3216X5R1C106KT or equivalent) ceramic capacitors placed across V_{IN} to P_{GND} pins.

(3) System conditions as defined in Note 1. Peak output current is applied for $t_p = 50\text{ }\mu\text{s}$.

6.4 Thermal Information

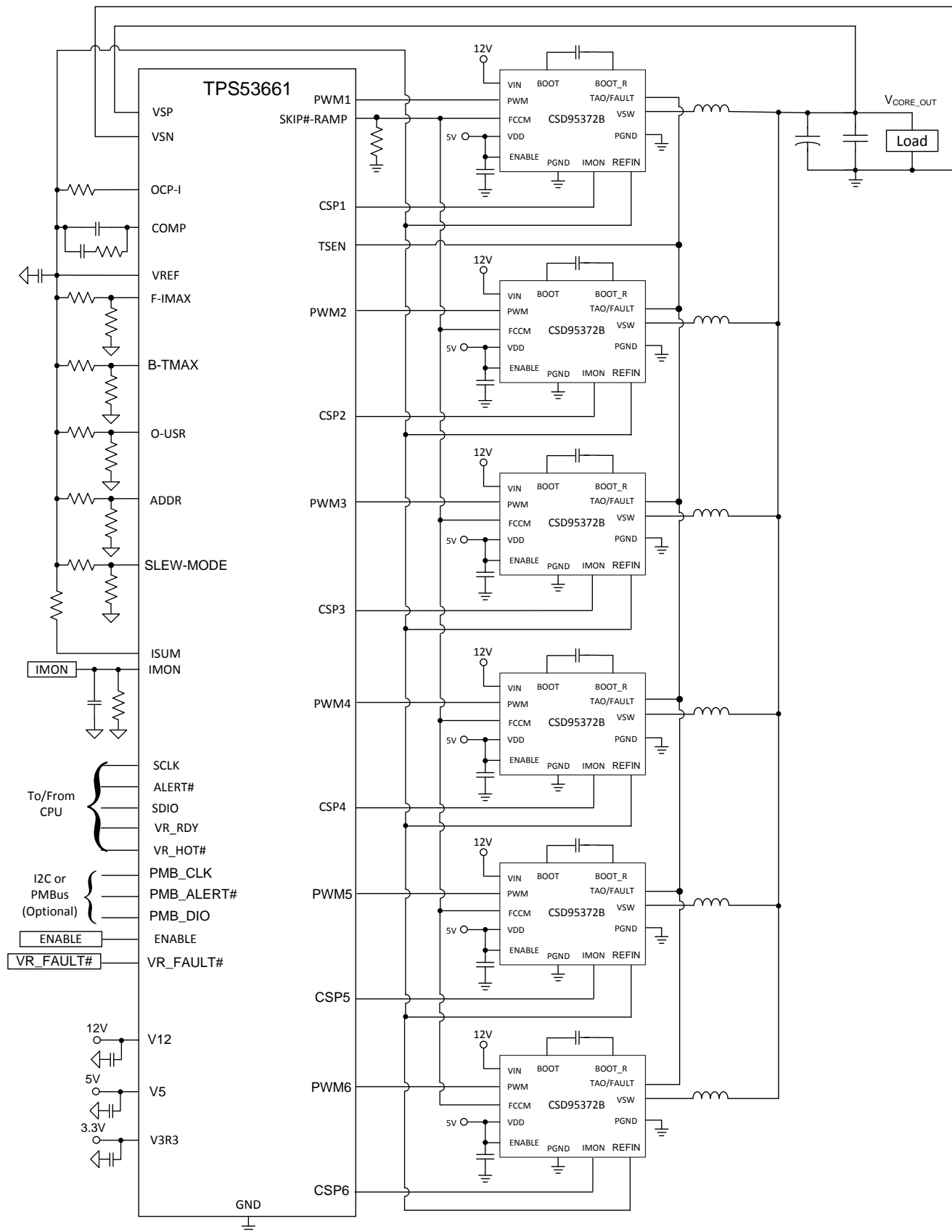
 $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

| | THERMAL METRIC | MIN | TYP | MAX | UNIT |
|-----------------|---|-----|-----|-----|----------------------|
| $R_{\theta JC}$ | Junction-to-Case Thermal Resistance (Top of package) ⁽¹⁾ | | | 15 | $^{\circ}\text{C/W}$ |
| $R_{\theta JB}$ | Junction-to-Board Thermal Resistance ⁽²⁾ | | | 1.5 | |

(1) $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45 -cm²), 2-oz (.071-mm thick) Cu pad on a 1.5-inches x 1.5-inches, 0.06-inch (1.52-mm) thick FR4 board.

(2) $R_{\theta JB}$ value based on hottest board temperature within 1 mm of the package.

7 Application Schematic



8 Device and Documentation Support

8.1 Trademarks

NexFET, DualCool are trademarks of Texas Instruments.

8.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

8.3 Glossary

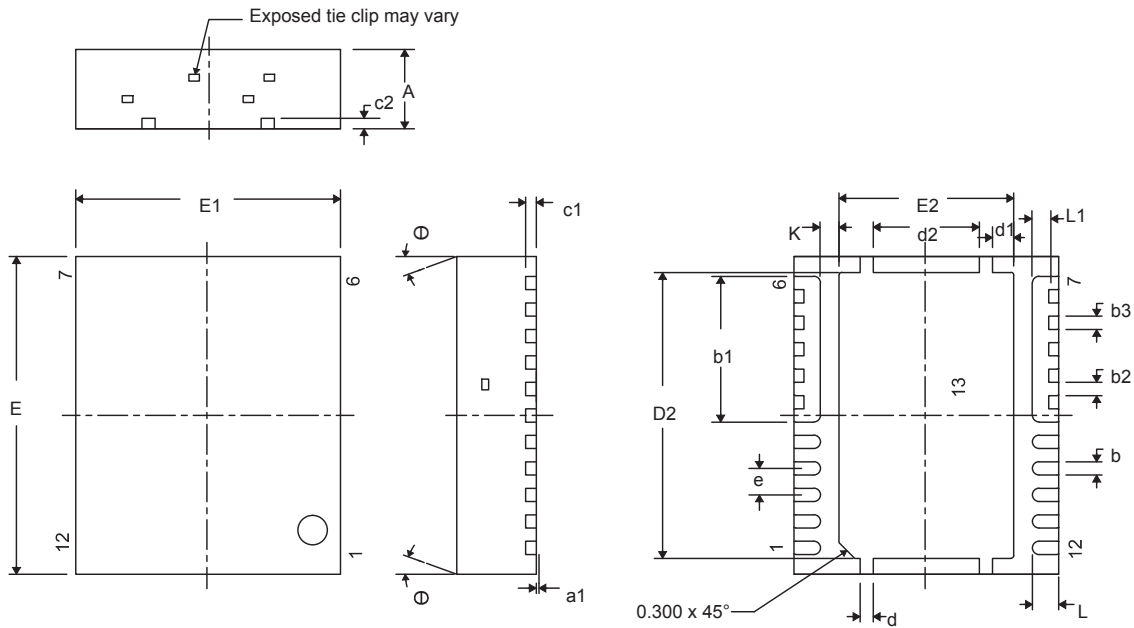
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms and definitions.

9 Mechanical, Packaging, and Orderable Information

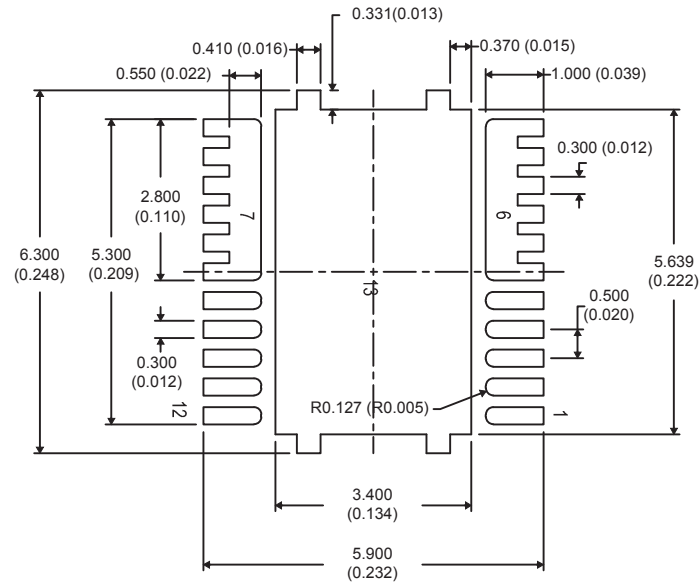
The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

9.1 Mechanical Drawing



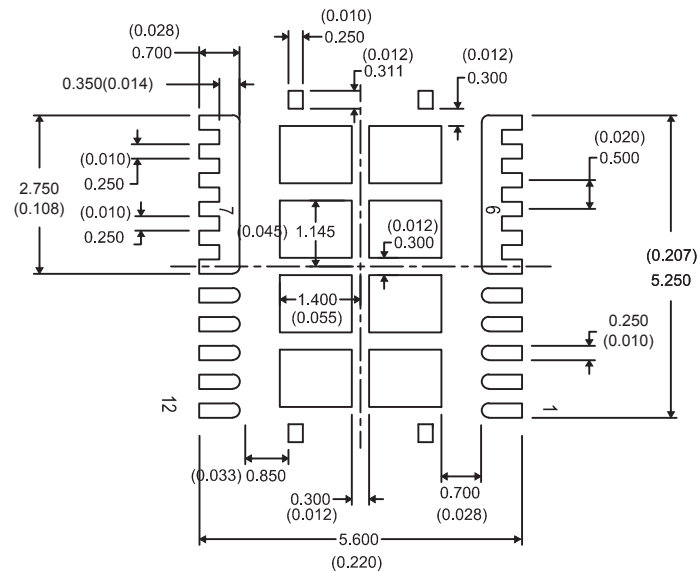
| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|-------|-------|-----------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 1.400 | 1.450 | 1.500 | 0.057 | 0.059 | 0.061 |
| a1 | 0.000 | 0.000 | 0.050 | 0.000 | 0.000 | 0.002 |
| b | 0.200 | 0.250 | 0.320 | 0.008 | 0.010 | 0.013 |
| b1 | 2.750 TYP | | | 0.108 TYP | | |
| b2 | 0.200 | 0.250 | 0.320 | 0.008 | 0.010 | 0.013 |
| b3 | 0.250 TYP | | | 0.010 TYP | | |
| c1 | 0.150 | 0.200 | 0.250 | 0.006 | 0.008 | 0.010 |
| c2 | 0.200 | 0.250 | 0.300 | 0.008 | 0.010 | 0.012 |
| D2 | 5.300 | 5.400 | 5.500 | 0.209 | 0.213 | 0.217 |
| d | 0.200 | 0.250 | 0.300 | 0.008 | 0.010 | 0.012 |
| d1 | 0.350 | 0.400 | 0.450 | 0.014 | 0.016 | 0.018 |
| d2 | 1.900 | 2.000 | 2.100 | 0.075 | 0.079 | 0.083 |
| E | 5.900 | 6.000 | 6.100 | 0.232 | 0.236 | 0.240 |
| E1 | 4.900 | 5.000 | 5.100 | 0.193 | 0.197 | 0.201 |
| E2 | 3.200 | 3.300 | 3.400 | 0.126 | 0.130 | 0.134 |
| e | 0.500 TYP | | | 0.020 TYP | | |
| K | 0.350 TYP | | | 0.014 TYP | | |
| L | 0.400 | 0.500 | 0.600 | 0.016 | 0.020 | 0.024 |
| L1 | 0.210 | 0.310 | 0.410 | 0.008 | 0.012 | 0.016 |
| θ | 0.00 | — | — | 0.00 | — | — |

9.2 Recommended PCB Land Pattern



1. Dimensions are in mm (inches).

9.3 Recommended Stencil Opening



1. Dimensions are in mm (inches).
2. Stencil thickness is 100 μm .

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| CSD95372BQ5M | ACTIVE | LSON-CLIP | DQP | 12 | 2500 | Pb-Free (RoHS Exempt) | CU NIPDAU | Level-2-260C-1 YEAR | | 95372BM | Samples |
| CSD95372BQ5MT | ACTIVE | LSON-CLIP | DQP | 12 | 250 | Pb-Free (RoHS Exempt) | CU NIPDAU | Level-2-260C-1 YEAR | 0 to 0 | 95372BM | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

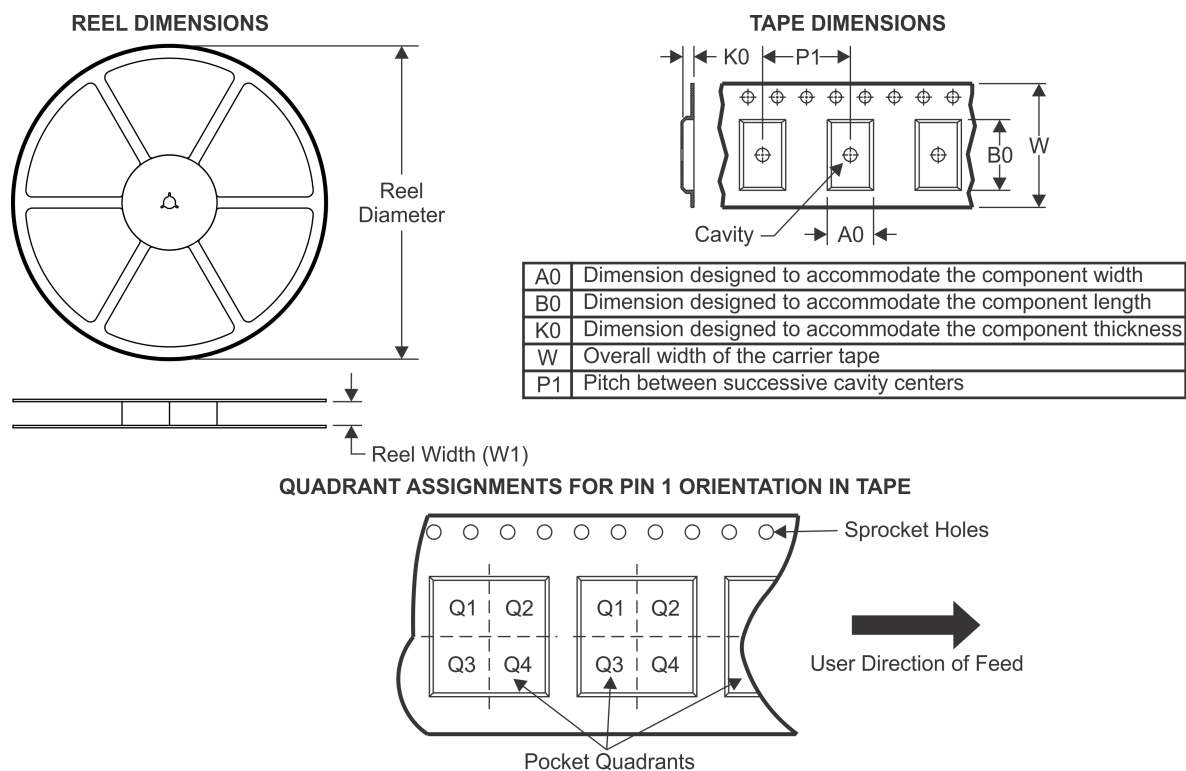
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| CSD95372BQ5M | LSON-CLIP | DQP | 12 | 2500 | 330.0 | 12.4 | 5.3 | 6.3 | 1.8 | 8.0 | 12.0 | Q1 |
| CSD95372BQ5MT | LSON-CLIP | DQP | 12 | 250 | 180.0 | 12.4 | 5.3 | 6.3 | 1.8 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CSD95372BQ5M | LSON-CLIP | DQP | 12 | 2500 | 367.0 | 367.0 | 35.0 |
| CSD95372BQ5MT | LSON-CLIP | DQP | 12 | 250 | 210.0 | 185.0 | 35.0 |

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